



U74HC2G32

CMOS IC

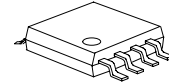
2-INPUT OR GATE

DESCRIPTION

The U74HC2G32 is a 2-input OR gate which provides the Function $Y=A+B$.

FEATURES

- * Operation Voltage Range: 2.0~6.0V
- * Low Power Dissipation: $I_{CC}=10\mu A(\text{Max})$
- * High Speed: $t_{pd}=9\text{ns}(V_{CC}=4.5\text{V}, C_L=50\text{pF})$
- * Specified from -40 to $+85^{\circ}\text{C}$ and -40 to $+125^{\circ}\text{C}$



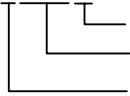
MSOP-8

*Pb-free plating product number:
U74HC2G32L

ORDERING INFORMATION

Order Number		Package	Packing
Normal	Lead Free Plating		
U74HC2G32-SM1-R	U74HC2G32L-SM1-R	MSOP-8	Tape Reel
U74HC2G32-SM1-T	U74HC2G32L-SM1-T	MSOP-8	Tube

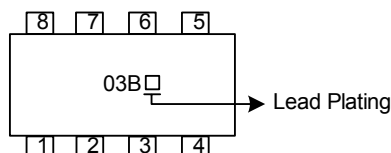
U74HC2G32L-SM1-R



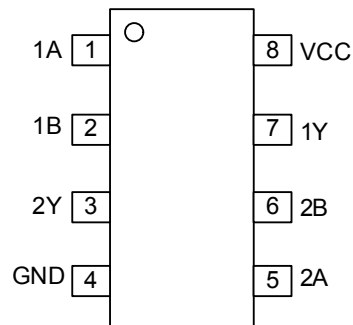
- (1) Packing Type
- (2) Package Type
- (3) Lead Plating

- (1) R: Tape Reel, T: Tube
- (2) SM1: MSOP-8
- (3) L: Lead Free Plating, Blank: Pb/Sn

MARKING



■ PIN CONFIGURATION



■ FUNCTION TABLE (each gate)

INPUT		OUTPUT
A	B	Y
L	L	L
L	H	H
H	L	H
H	H	H

■ LOGIC DIAGRAM (positive logic)



■ **ABSOLUTE MAXIMUM RATING** (unless otherwise specified)(Note 1)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V_{CC}	-0.5~7	V
Input Voltage	V_{IN}	-0.5~7	V
Output Voltage	V_{OUT}	-0.5~ $V_{CC}+0.5$	V
Input Clamp Current	I_{IK}	± 20	mA
Output Clamp Current	I_{OK}	± 20	mA
Output Current	I_{OUT}	25	mA
V_{CC} or GND Current	I_{CC}	50	mA
Power Dissipation	P_D	300	mW
Storage Temperature	T_{STG}	-65 ~ +150	°C

Note 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}		2.0	5.0	6.0	V
Input Voltage	V_{IN}		0		V_{CC}	V
Output Voltage	V_{OUT}		0		V_{CC}	V
Input Transition Rise or Fall Times	t_R, t_F	$V_{CC}=2.0V$			1000	ns
		$V_{CC}=4.5V$		6	500	
		$V_{CC}=6V$			400	
Operating Temperature	T_A		-40	25	125	°C

■ **STATIC CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDITIONS	$T_A=25^{\circ}C$			-40~85°C		-40~125°C		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
High-Level Input Voltage	V_{IH}	$V_{CC}=2.0V$	1.5	1.2		1.5		1.5		V
		$V_{CC}=4.5V$	3.15	2.4		3.15		3.15		
		$V_{CC}=6.0V$	4.2	3.2		4.2		4.2		
Low-Level Input Voltage	V_{IL}	$V_{CC}=2.0V$		0.8	0.5		0.5		0.5	V
		$V_{CC}=4.5V$		2.1	1.35		1.35		1.35	
		$V_{CC}=6.0V$		2.8	1.8		1.8		1.8	
High-Level Output Voltage	V_{OH}	$V_{CC}=2.0V, I_{OH}=-20\mu A$	1.9	2.0		1.9		1.9		V
		$V_{CC}=4.5V, I_{OH}=-20\mu A$	4.4	4.5		4.4		4.4		
		$V_{CC}=6.0V, I_{OH}=-20\mu A$	5.9	6.0		5.9		5.9		
		$V_{CC}=4.5V, I_{OH}=-4mA$	4.18	4.32		4.13		3.7		
		$V_{CC}=6.0V, I_{OH}=-5.2mA$	5.68	5.81		5.63		5.2		
Low-Level Output Voltage	V_{OL}	$V_{CC}=2.0V, I_{OL}=20\mu A$		0	0.1		0.1		0.1	V
		$V_{CC}=4.5V, I_{OL}=20\mu A$		0	0.1		0.1		0.1	
		$V_{CC}=6.0V, I_{OL}=20\mu A$		0	0.1		0.1		0.1	
		$V_{CC}=4.5V, I_{OH}=4mA$		0.15	0.26		0.33		0.4	
		$V_{CC}=6.0V, I_{OH}=5.2mA$		0.16	0.26		0.33		0.4	
Input Leakage Current	$I_{I(LEAK)}$	$V_{CC}=6.0V, V_{IN}=V_{CC}$ or GND			± 0.1		± 1		± 1	μA
Quiescent Supply Current	I_Q	$V_{CC}=6.0V, V_{IN}=V_{CC}$ or GND, $I_{OUT}=0$			1		10		20	μA
Input Capacitance	C_{IN}	$V_{CC}=5.0V, V_{IN}=V_{CC}$ or GND		1.5						pF

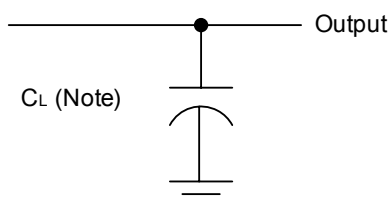
■ **DYNAMIC CHARACTERISTICS** (Input: $t_R, t_F \leq 6\text{ns}$; PRR $\leq 1\text{MHz}$)

See Fig-1 and Fig-2 for test circuit and waveforms.

PARAMETER	SYMBOL	TEST CONDITIONS	T _A =25°C			-40~85°C		-40~125°C		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Propagation Delay From Input (A and B) to Output(Y)	t _{PHL} /t _{PLH}	V _{CC} = 2.0, C _L = 50pF		24	75		95		110	ns
		V _{CC} = 4.5, C _L = 50pF		9	15		19		22	
		V _{CC} = 6.0, C _L = 50pF		7	13		16		20	
Output Transition Time	t _{THL} /t _{TLH}	V _{CC} = 2.0, C _L = 50pF		18	75		95		125	ns
		V _{CC} = 4.5, C _L = 50pF		6	15		19		25	
		V _{CC} = 6.0, C _L = 50pF		5	13		16		20	
Operating Characteristics										
PARAMETER		SYMBOL	TEST CONDITIONS						TYP	UNIT
Power Dissipation Capacitance		Cpd	No load, f=1MHz, V _{CC} =5						10	pF

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■ TEST CIRCUIT AND WAVEFORMS



Note: C_L includes probe and jig capacitance.

Fig.1 Load circuitry for switching times.

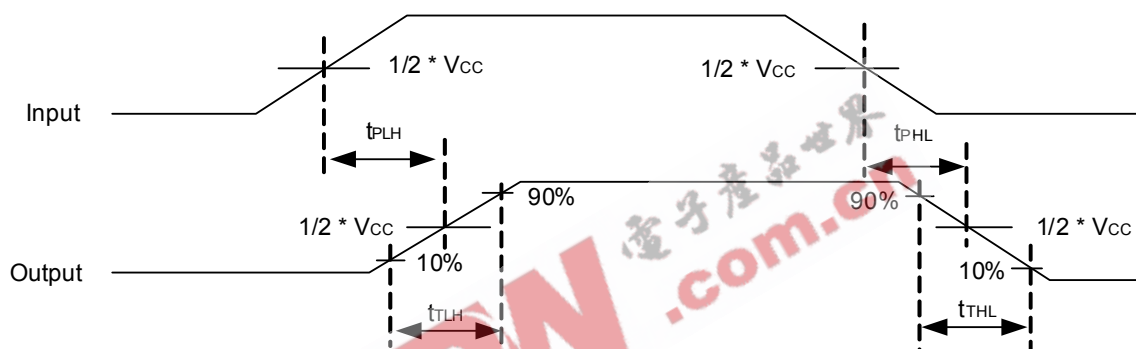


Fig. 2 Propagation delay from input(A and B) to output(Y) and Output transition time.

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